

# 635nm Laser Diode

 CHANGCHUN NEW INDUSTRIES  
OPTOELECTRONICS TECH CO., LTD.

## ■ Features

Output Power: 20mW (CW)

Standard TO-18 Package



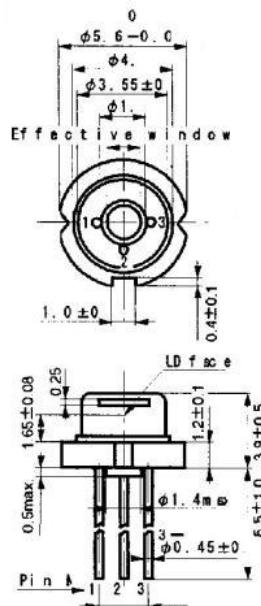
## ■ Absolute Maximum Ratings

(Tc=25°C)

Item	Symbol	Absolute Maximum Ratings	Unit
Light Output Power	Po	20	mW
LD Reverse Voltage	Vr (LD)	2	V
PD Reverse Voltage	Vr (PD)	30	V
Storage Temperature	Tstg	-40~85	°C
Operating Case Temperature	Tc	-10~50	°C

## Outline Dimension

### TO-18 Package



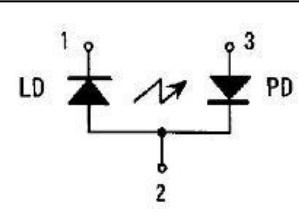
(Unit: mm)

## ■ Initial Electrical/Optical Characteristics

(Tc=25°C)

Item	Symbol	Typ.	Unit
Optical Output	Po	20	mW
Peak Wavelength*	λp	635±5	nm
Threshold Current	Ith	60	mA
Operating Current	Iop	80	mA
Slope Efficiency	η	1.0	mW/mA
Operating Voltage	Vop	2.3	V
Horizontal Beam Divergence	θ//	8	deg.
Vertical Beam Divergence	θ⊥	16	deg.

## Pin Connection



\* Measuring specifications.

All figures in this specification are measured by CNI's method and may contain measurement deviations.

The above specifications are for reference purpose only and subjected to change without prior notice.



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